Erratum (v. 5, n. 4, 427-432, 2002)

Due to problems in the desktop publishing, the article

Homogeneous Gaussian Profile P+-Type Emitters: Updated Parameters and Metal-Grid Optimization,

by M. Cid, N. Stern*, was printed with figures caption error. The correct figures are:

**Figure 5.** Emitter collection efficiency, $\eta_c$ as function of emitter sheet resistivity, $R_s$ and surface doping level, $N_s$, considering passivated surfaces.

**Figure 6.** Short-circuit current density, $J_{sc}$ as function of emitter sheet resistivity, $R_s$ and surface doping level, $N_s$, considering p-type emitter solar cells.

**Figure 7.** Open circuit voltage, $V_{oc}$ as function of emitter sheet resistivity, $R_s$ and surface doping level, $N_s$, considering p-type emitter solar cells.

**Figure 8.** Efficiency, $\eta$ as function of emitter sheet resistivity, $R_s$ and surface doping level, $N_s$, considering p-type emitter solar cells.

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